Ground Fault Circuit Interrupter (GFCI)

Description

The NCS37000 is a fully UL943 compliant signal processor for GFCI applications. The device integrates a flexible power supply (including both shunt and LDO regulators), differential fault, and grounded-neutral detection circuits. Proprietary impedance measurement and signal processing techniques are used to minimize the number of external components and improve performance. The device also includes a specialized DSP controller that offers best in class immunity to nuisance loads without the need for external analog filters.

Features

- 6.0 12 Volt Operation (120 480 V AC mains with the appropriate series impedance)
- -40 to 85°C
- Very Low Power Consumption: <5 mW @ 5 V
- 16 Pin QFN Package or 20 Pin TSSOP Package
- Single Current Transformer (CT) Detection of both Differential and Grounded–Neutral Faults
- Self Syncing Internal Oscillator Adjusts to AC Mains Frequency to Guarantee Full Resolution on 50 and 60 Hz Distribution Systems
- Optimized Solenoid Deployment (coil is not energized near the AC mains zero crossings)
- Randomized Testing Sequence to Minimize Noise and Potential Interactions on the AC Mains
- >5 mA SCR Driver for use with High Igt SCR's for Improved Noise Immunity
- Superior Immunity to Nuisance Loads/Noise (up to 10 A) without Loss of Detection Capability or CT Saturation
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

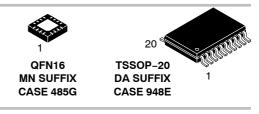
Typical Applications

- Load Panel GFCI Breakers
- GFCI Receptacles
- In-line GFCI Circuits (power cords)

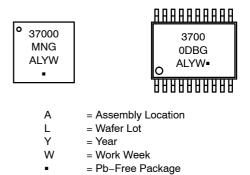


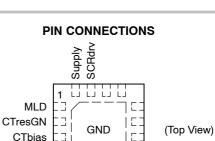
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MARKING DIAGRAMS





ORDERING INFORMATION

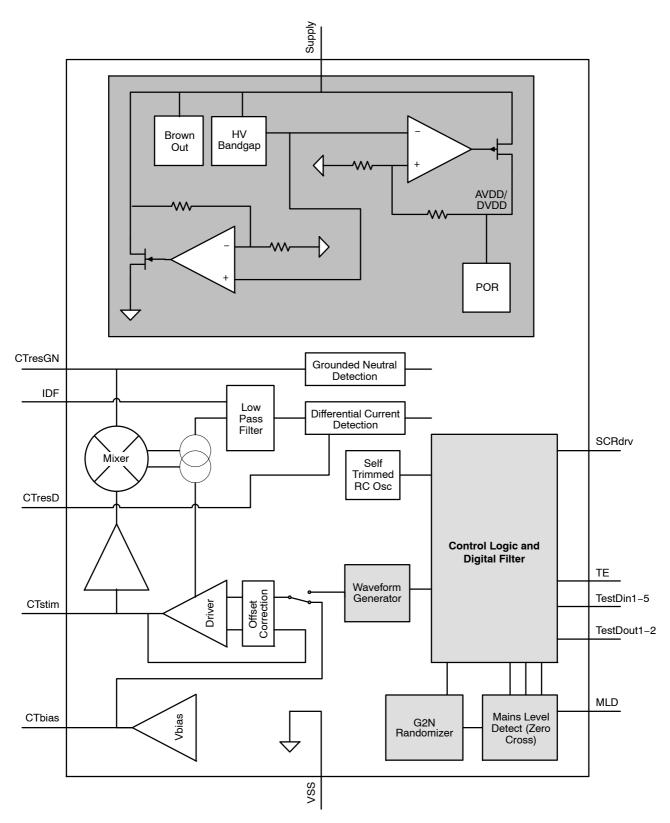
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CTresD

CTstim

Device	Package	Shipping [†]
NCS37000MNTWG	QFN16	2500/Tape & Reel
NCS37000MNG	(Pb-Free)	120 Units / Tube
NCS37000DBRG	TSSOP20	2500/Tape & Reel
NCS37000DBG	(Pb-Free)	74 Units / Tube

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.





Pin #	Name	Pad Description			
0	Ground	QFN center slug			
1	MLD	Mains Level Detect (Zero Cross)			
2	CTresGN	Determines IV converter gain for detection threshold / matched to CT turns ratio (Ground-Neutral)			
3	CTbias	Direct connection to the CT			
4	CTstim	Direct connection to the CT			
5	CTresD	Determines IV converter gain for detection threshold / matched to CT turns ratio (Differential Current)			
6	IDF	Front end noise filter capacitor			
7	NC	Tie to Ground or leave floating			
8	NC	Float			
9	NC	Tie to Ground or leave floating			
10	NC	Tie to Ground or leave floating			
11	NC	Tie to Ground or leave floating			
12	NC	Tie to Ground or leave floating			
13	NC	Float			
14	NC	Float			
15	SCRdrv	Used to trigger the solenoid at a fault detection			
16	Supply	Power supply			

Table 1. PIN FUNCTION DESCRIPTION – QFN

Table 2. PIN FUNCTION DESCRIPTION – TSSOP

Pin #	Name Pad Description			
1	CTstim	Differential and ground to neutral stimulus point for the current transformer		
2	Ground	Ground connection for IC		
3	CTresD	Determines IV converter gain for detection threshold / matched to CT turns ratio (Differential Current)		
4	IDF	Determines corner frequency of the differential current path filter		
5	GFtest	Output to induce external differential current		
6	NC	Tie to Ground or leave floating		
7	NC	Float		
8	NC	Tie to Ground or leave floating		
9	NC	Tie to Ground or leave floating		
10	NC	Tie to Ground or leave floating		
11	Ground	Ground connection for IC		
12	NC	Float		
13	NC	Float		
14	SCRdrv Used to trigger the solenoid at a fault detection			
15	DVDD	Internal digital 5 V regulated supply		
16 AVDD Internal analog 5 V regulated supply		Internal analog 5 V regulated supply		
17	Supply	12 V shunt regulated power supply		
18	MLD	Mains Level Detect (Zero Cross) and AM slope detect (for oscillator sync/trim and AM init)		
19	CTresGN	Determines IV converter gain for detection threshold / matched to CT turns ratio (Ground-Neutral)		
20	CTbias	External 2 V bias for the current transformer		

Table 3. ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Supply Voltage Range	Vs	6.0 to 12 V	V	
Input Voltage Range (Note 1)	V _{in}	–0.3 to 6.0	V	
Output Voltage Range	V _{out}	–0.3 to 6.0 V or (V _{in} + 0.3), whichever is lower	V	
Maximum Junction Temperature	T _{J(max)}	140	°C	
Storage Temperature Range	T _{STG}	–65 to 150	°C	
ESD Capability, Human Body Model (Note 2)	ESD _{HBM}	2	kV	
ESD Capability, Machine Model (Note 2)	ESD _{MM}	200	V	
Lead Temperature Soldering Reflow (SMD Styles Only), Pb-Free Versions (Note 3)	T _{SLD}	260	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Refer to ELÉCTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

2. This device series incorporates ESD protection and is tested by the following methods:

ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)

ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)

Latchup Current Maximum Rating: ≤ 150 mA per JEDEC standard: JESD78

3. For information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

Table 4. THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, QFN16, 3x3.3 mm (Note 4) Thermal Resistance, Junction-to-Air (Note 5)	R_{\thetaJA}	64	°C/W
Thermal Characteristics, TSOP-5 (Note 4) Thermal Resistance, Junction-to-Air (Note 5)	$R_{ hetaJA}$	118.6	°C/W

4. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

5. Values based on copper area of 645 mm² (or 1 in²) of 1 oz copper thickness and FR4 PCB substrate.

Table 5. OPERATING RANGES (Note 6)

Parameter	Conditions	Min	Тур	Max	Units
Operating Temperature		-40		85	С
IDD in typical power state			2.0		mA
Stimulus Generator Frequency	Tri-tone	3.1		3.4	kHz
SCR Trigger Current				8.0	mA
SCR Trigger output voltage	With 5 V supply	4.5		5.5	V
Fault Current Sensitivity	Programmable with CTresD	4.6	4.8	5.0	mA
Ground Fault Response Time	5 – 20 mA		150		ms
Ground Fault Response Time	20 – 40 mA		75		ms
Ground Fault Response Time	>40 mA		25		ms
Saturation Fault Response Time	>300 mA		1.4		ms
CT Turns Ratio		200		300	
Ground - Neutral Detection Threshold	Total series impedance (Rn and Rg)	3.0		6.0	Ω
Internal Oscillator Frequency			2.0		MHz
CT Stimulus Current	Internally limited			1.0	mA
CT Driver Closed Loop BW				500	kHz

6. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

APPLICATIONS INFORMATION

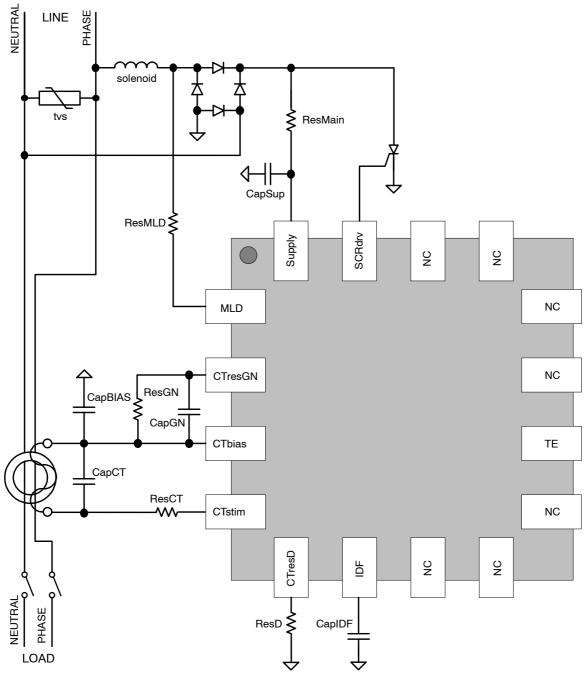


Figure 2. Typical Application Schematic

Component Type	Instance	Value	Note ON-MCR08	
SCR	Q1	-		
Diode	Dx	-	ON-1N4007	
Capacitor	Csup	1 – 5 μF	For a full bridge rectifier	
Capacitor	Cgn	2 – 10 nF	Low pass corner frequency for GN detection	
Capacitor	Cidf	220 nF	1kHz differential corner frequency	
Capacitor	Cct	2.2 – 5 nF	Match to current transformer for resonance	
Capacitor	Cbias	10 nF	Added for filtering	
Resistor	RctresD	40 – 80K	Matched to current transformer	
Resistor	RctGN	100 – 400K	Matched to current transformer	
Resistor	Rzc	400 – 800K	Zero cross detector shunt resistance	
Resistor	Rmains	10 – 20K	For a full bridge rectifier	
TVS	T1	-	~250 – 400 V	

RECOMMENDED EXTERNAL COMPONENTS:

Filtering

The analog signal capture portion of the IC includes a single pole filter that can be set externally with Cidf. This provides an additional layer of protection against false tripping under steady state noise conditions. High frequency steady state noise is common with pumps, motors or other cyclic noise generators.

Cidf = 220 nF = 1 KHz low pass.

Setting Trip Sensitivity

The CTresD resistor sets the threshold for the differential current fault levels. Increasing CTresD causes the fault levels to trip at lower differential currents. CT efficiency at 60 Hz must be considered.

CTresD= 200*#Turns – Subject to CT efficiency at 60 Hz

The CTresGN resistor sets the threshold for ground to neutral fault detection. The Rt parameter is the desired

ground to neutral resistance trip level. Higher CTresGN values will cause the part to trip at higher ground to neutral impedances.

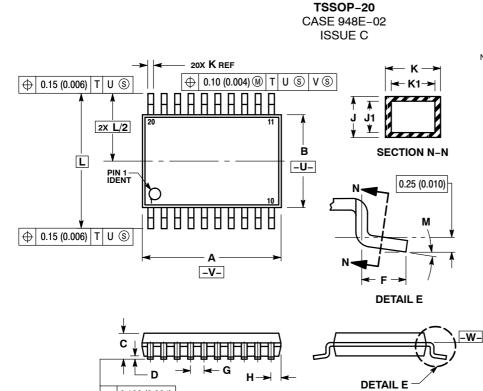
CtresGN = #Turns² x Rt/2 – Subject to CT efficiency from 3 kHz to 4 kHz

Setting Grounded-Neutral response time

Cgn is used to define the response time of the grounded-neutral detection circuit. The analog portion converts the impedance into a DC voltage and a high frequency (aliased) component. The capacitor is used to remove the high frequency component leaving just the DC representation of the impedance.

CTcapGN= 1.8E-4/CTresGN

PACKAGE DIMENSIONS



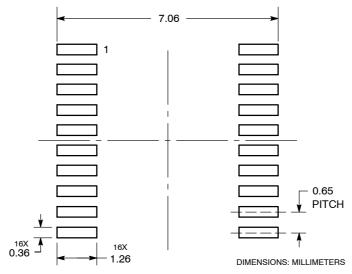
○ 0.100 (0.004)

NOTES: 1. DIMENSIONING AND TOLERANCING PER

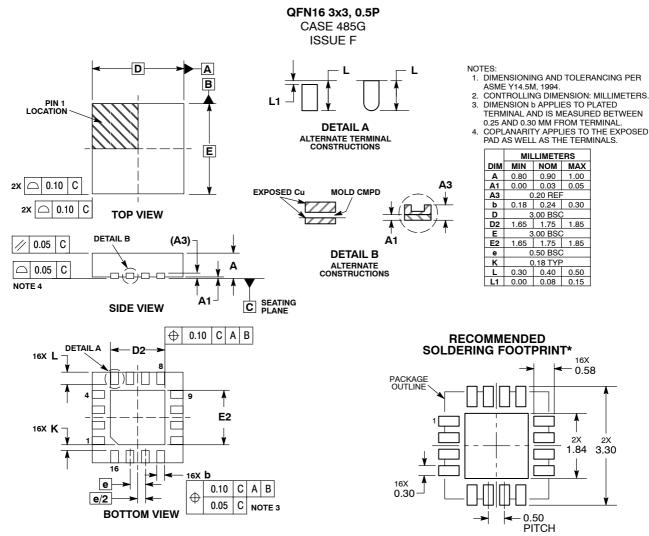
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- REFERENCE ONLY. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-. 7.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN MAX	
Α	6.40	6.60	0.252	0.260
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.27	0.37	0.011 0.01	
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
М	0°	8°	0 °	8°

SOLDERING FOOTPRINT



PACKAGE DIMENSIONS



DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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